

## Supporting information

### Transparent supercapacitors of 2-nm ruthenium oxide nanoparticles decorated on 3D nitrogen-doped graphene aerogel

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#### Calculation method

Based on the XRD result, the interlayer distance ( $d_{\text{spacing}}$ ) of both samples can be calculated by using the Bragg's law in equation (1)<sup>1</sup>;

$$2d \sin\theta = n\lambda \quad (1)$$

where  $d$  is the interlayer distance,  $\theta$  is the scattering angle,  $\lambda$  is the incident X-ray wavelength (1.5418 Å).

Based on the CV result, the specific ( $C_{\text{sp}}$ ) and areal ( $C_{\text{ae}}$ ) capacitances of the electrode can be calculated by the following equation (2) and (3):

$$C_{\text{sp}} = 4 \frac{\int IdV}{(2vm\Delta V)} \quad (2)$$

$$C_{\text{ae}} = 4 \frac{\int IdV}{(2vA\Delta V)} \quad (3)$$

where  $I$  is the current,  $V$  is the cell voltage,  $v$  is the scan rate,  $m$  is the total mass of active material,  $A$  is the total effective area of the device (8 cm<sup>2</sup>), and  $\Delta V$  is the working cell voltage window.

Based on the GCD result, the specific ( $C_{\text{sp}}$ ) and areal ( $C_{\text{ae}}$ ) capacitances from GCD curves were calculated by the following equation (4)<sup>2</sup> and (5)<sup>3</sup>:

$$C_{\text{sp}} = 4 \frac{I\Delta t}{m\Delta V} \quad (4)$$

$$C_{ae} = 4 \frac{I \Delta t}{A \Delta V} \quad (5)$$

where  $I$  is the applied current,  $\Delta t$  is the discharge time,  $\Delta V$  is the cell voltage window excluding the  $iR$  drop,  $m$  is the total mass of active material, and  $A$  is the total effective area of the device (8 cm<sup>2</sup>).

Based on the EIS result, the complex power can be calculated by using equation (6)-(9):

$$P(\omega) = \omega C''(\omega) |\Delta V_{rms}|^2 \quad (6)$$

$$Q(\omega) = -\omega C'(\omega) |\Delta V_{rms}|^2 \quad (7)$$

$$S(\omega) = P(\omega) + jQ(\omega) \quad (8)$$

$$|\Delta V_{rms}|^2 = \frac{\Delta V_{max}}{\sqrt{2}} \quad (9)$$

where  $V_{max}$  is the maximum amplitude of applied ac perturbation (5 mV),  $j$  is an imaginary number,  $\omega$  is an angular frequency ( $\omega=2\pi f$ ). The  $C'$  and  $C''$  are the real and imaginary parts of the complex capacitance which can be calculated by (10) and (11):

$$C'(\omega) = -Z''(\omega) / \{\omega |Z(\omega)|^2\} \quad (10)$$

$$C''(\omega) = Z'(\omega) / \{\omega |Z(\omega)|^2\} \quad (11)$$

where  $Z'$  and  $Z''$  are the real and imaginary parts of the complex impedance  $Z$ , respectively.

The relaxation time constant ( $\tau_0$ ) can be calculated by equation (12):

$$\tau_0 = \frac{1}{2\pi f_0} \quad (12)$$

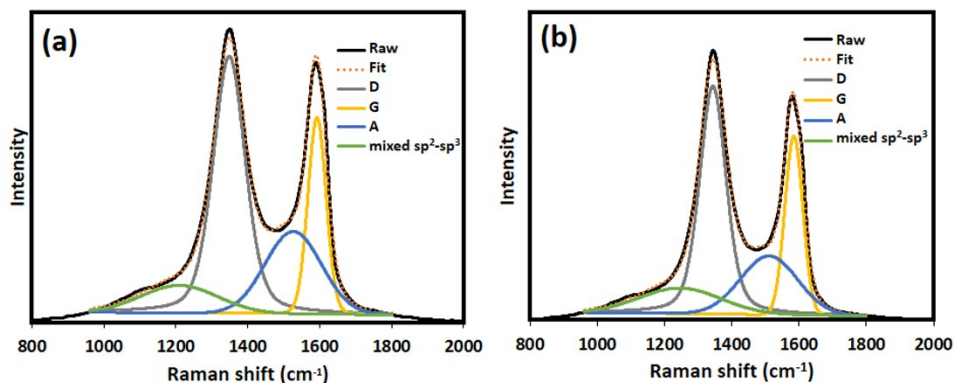
where  $f_0$  is a relaxation frequency.

For the Ragone plot, the areal energy ( $E$ ) and areal power ( $P$ ) can be calculated by using the following equation (13) and (14):

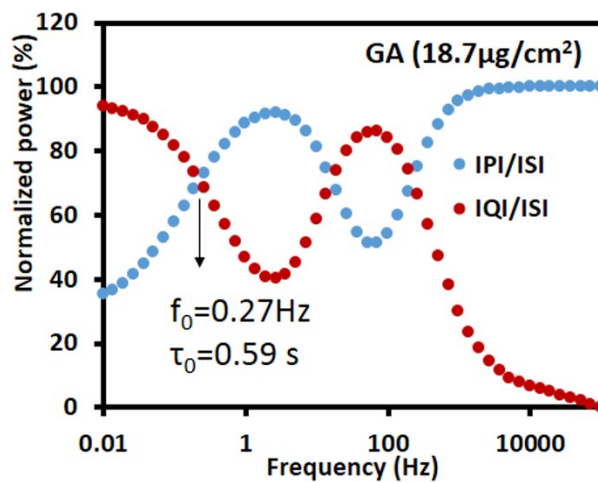
$$E = \frac{1}{2} C_{cell} \Delta V^2 \quad (13)$$

$$P = \frac{E}{t} \quad (14)$$

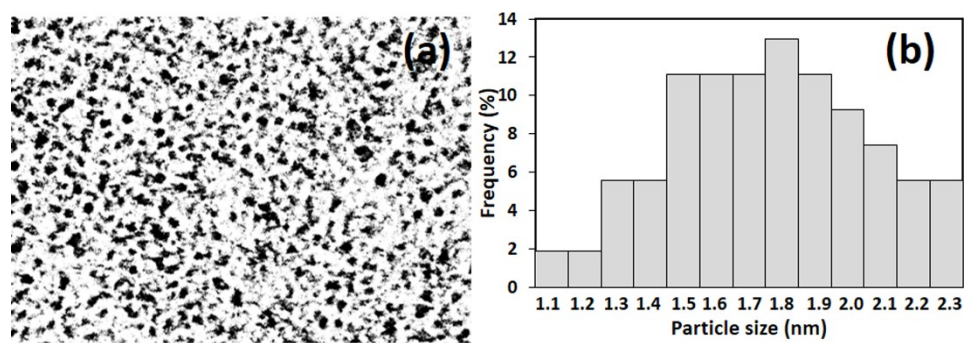
where  $C_{cell}$  is the areal capacitance of a cell,  $\Delta V$  is the cell voltage window excluding the  $iR$  drop, and  $t$  is the discharge time<sup>4</sup>.



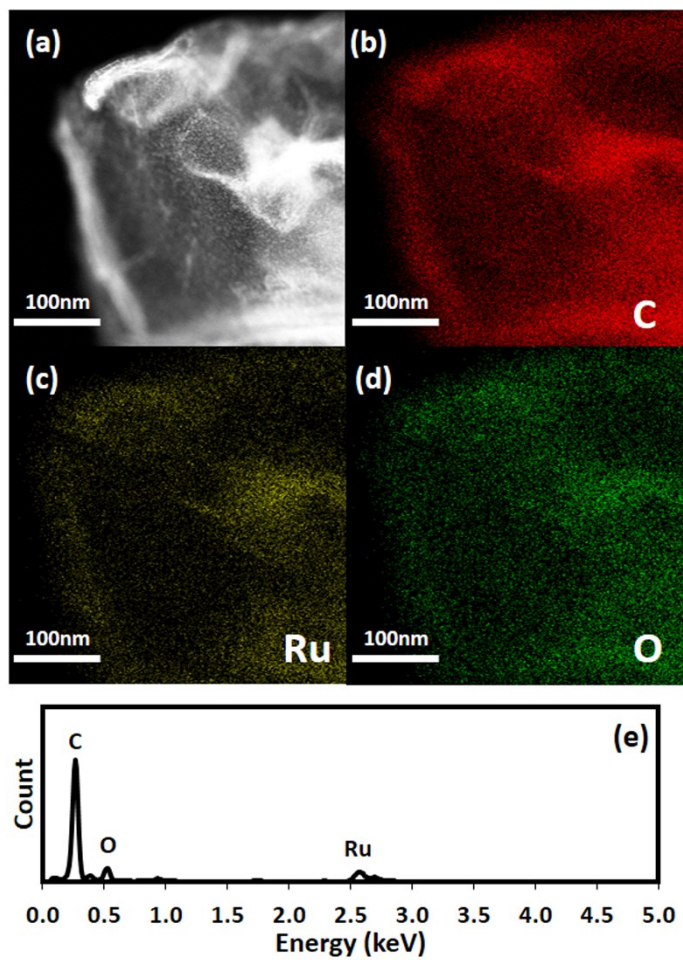
**Fig. S1.** Deconvoluted Raman spectra of (a) bare NGA and (b) RuO<sub>2</sub>/NGA.



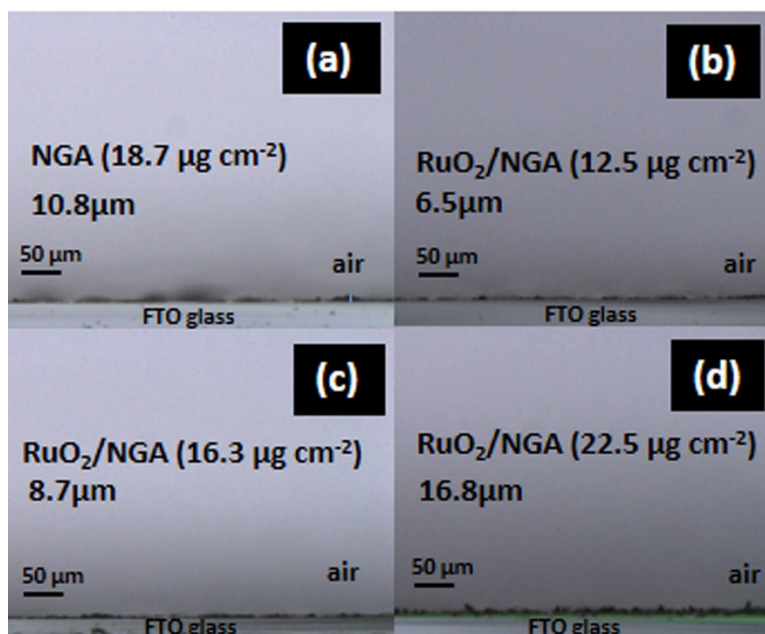
**Fig. S2.** Complex power analysis of the as-fabricated bare NGA supercapacitor at a mass loading of 18.7  $\mu\text{g cm}^{-2}$ .



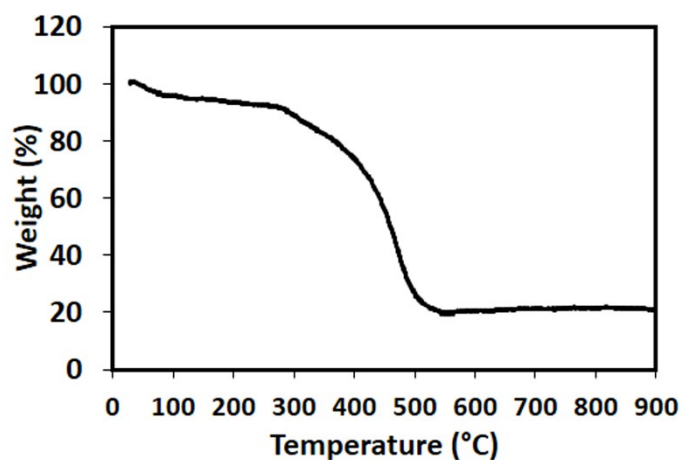
**Fig. S3.** (a) TEM image after processed using the ImageJ program and (b) the particle size distribution of RuO<sub>2</sub> nanoparticles on NGA.



**Fig. S4.** (a) STEM image, EDS elemental mapping data for (b) C, (c) Ru, (d) O, and (e) EDS spectrum of RuO<sub>2</sub>/NGA.



**Fig. S5.** Cross-section optical micrographs of (a) NGA ( $18.7 \mu\text{g cm}^{-2}$ ) and  $\text{RuO}_2/\text{NGA}$  with different mass loadings, (b)  $12.5$ , (c)  $16.3$ , and (d)  $22.5 \mu\text{g cm}^{-2}$



**Fig. S6.** TGA thermogram of  $\text{RuO}_2/\text{NGA}$  under  $\text{O}_2$  atmosphere at a heating rate of  $10^\circ\text{C min}^{-1}$ .

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Electrode	%T of the device	Areal Capacitance of electrode (mF cm <sup>-2</sup> )	Condition	Electrolyte	Reference
Cellulose nanofiber-RGO10	56	0.66	5 mV s <sup>-1</sup>	H <sub>2</sub> SO <sub>4</sub> -PVA	5
Cellulose nanofiber-RGO20	30	0.78	5 mV s <sup>-1</sup>	H <sub>2</sub> SO <sub>4</sub> -PVA	5
PANI/SWCNT	55	0.55	26 μA cm <sup>-2</sup>	H <sub>2</sub> SO <sub>4</sub>	6
Wrinkled graphene	57	0.0058	0.8 μA	H <sub>3</sub> PO <sub>4</sub> -PVA	7
Aligned CNTs	75	0.0038	100 mV s <sup>-1</sup>	H <sub>3</sub> PO <sub>4</sub> -PVA	8
Graphene network	84	0.0042	0.1 μA	H <sub>3</sub> PO <sub>4</sub> -PVA	9
CVD graphene	-	0.080	630 mA cm <sup>-2</sup>	H <sub>3</sub> PO <sub>4</sub> -PVA	10
Reduced multilayer graphene oxide (RMGO)	-	0.394	281 nA cm <sup>-2</sup>	H <sub>3</sub> PO <sub>4</sub> -PVA	10
Few-layer graphene film	-	0.060	100 mV s <sup>-1</sup>	H <sub>3</sub> PO <sub>4</sub> -PVA	11
RuO <sub>2</sub> /PEDOT:PSS	80	0.84	10 mV s <sup>-1</sup>	H <sub>2</sub> SO <sub>4</sub> -PVA	12
NGA	53.6	0.77	9.35 μA cm <sup>-2</sup> (0.5A g <sup>-1</sup> )	H <sub>2</sub> SO <sub>4</sub> -PVA	This work
RuO <sub>2</sub> /NGA	34.1	1.57	8.15 μA cm <sup>-2</sup> (0.5A g <sup>-1</sup> )	H <sub>2</sub> SO <sub>4</sub> -PVA	This work

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